# FDT434P

April 2011

**FAIRCHILD** 

## FDT434P

### P-Channel 2.5V Specified PowerTrench<sup>®</sup> MOSFET

#### **General Description**

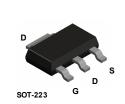
This P-Channel 2.5V specified MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain low gate charge for superior switching performance.

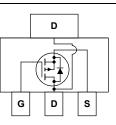
#### Applications

- Low Dropout Regulator
- DC/DC converter
- Load switch
- Motor driving

#### Features

- -5.5 A, -20 V.  $R_{DS(ON)}$  = 0.050  $\Omega$  @  $V_{GS}$  = -4.5 V  $R_{DS(ON)}$  = 0.070  $\Omega$  @  $V_{GS}$  = -2.5 V.
- Low gate charge (13nC typical)
- High performance trench technology for extremely low  $R_{\text{DS}(\text{ON})}$  .
- High power and current handling capability in a widely used surface mount package.





#### Absolute Maximum Ratings T<sub>A</sub>=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain-Source Voltage		-20	V
V <sub>GSS</sub>	Gate-Source Voltage		±8	V
ID	Drain Current – Continuous	(Note 1a)	-6	A
	– Pulsed		-30	
P <sub>D</sub>	Power Dissipation for Single Operation	(Note 1a)	3	W
		(Note 1b)	1.3	
		(Note 1c)	1.1	
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range		-55 to +150	°C

#### **Thermal Characteristics**

R <sub>eJA</sub>	Thermal Resistance, Junction-to-Ambient	(Note 1a)	42	°C/W		
R <sub>θJC</sub>	Thermal Resistance, Junction-to-Case	(Note 1)	12	°C/W		

#### Package Marking and Ordering Information

-	evice Reel S	Size Tape width	Quantity
434 FD	T434P 13'	' 12mm	2500 units

**Electrical Characteristics**  $T_{A} = 25^{\circ}C$  unless otherwise noted Symbol Min Parameter **Test Conditions** Тур Max Units **Off Characteristics** BV<sub>DSS</sub> Drain-Source Breakdown Voltage -20 V  $V_{GS} = 0 V, I_D = -250 \mu A$ Breakdown Voltage Temperature  $I_D = -250 \,\mu\text{A}$ , Referenced to  $25^{\circ}\text{C}$ -28 mV/°C  $\Delta BV_{DSS}$  $\Delta T_{\rm J}$ Coefficient  $V_{DS} = -16 V, V_{GS} = 0 V$ IDSS Zero Gate Voltage Drain Current -1 μA  $V_{DS} = 0 V$ Gate-Body Leakage Current, V<sub>GS</sub> = 8 V, 100 IGSSF nA Forward Gate-Body Leakage Current,  $V_{GS} = -8 V$  $V_{DS} = 0 V$ -100 IGSSR nA Reverse **On Characteristics** (Note 2) Gate Threshold Voltage  $V_{GS(th)}$  $V_{DS} = V_{GS}, I_D = -250 \overline{\mu A}$ -0.4 -0.6 -1 V Gate Threshold Voltage  $I_D = -250 \ \mu A$ , Referenced to  $25^{\circ}C$ 2 mV/°C  $\Delta V_{GS(th)}$ Temperature Coefficient  $\Delta T_{J}$ Static Drain-Source  $V_{GS} = -4.5 V_{,}$  $I_{D} = -6 A$ 0.040 0.050 R<sub>DS(on)</sub> Ω  $V_{GS} = -2.5 V$ ,  $I_{D} = -4 A$ **On-Resistance** 0.050 0.070 V<sub>GS</sub> = -4.5 V, I<sub>D</sub> = -6 A T<sub>J</sub>=125°C 0.067 0.083  $V_{DS}$  = -5 V **On–State Drain Current** V<sub>GS</sub> = -4.5 V, -20 А I<sub>D(on)</sub> Forward Transconductance  $V_{DS} = -10 V$ ,  $I_{D} = -6 A$ 6.5 S **g**<sub>FS</sub> **Dynamic Characteristics**  $V_{GS} = 0 V$ , Ciss Input Capacitance  $V_{DS} = -10 V$ , 1187 pF f = 1.0 MHz Coss **Output Capacitance** 270 pF **Reverse Transfer Capacitance** pF Crss 114 Switching Characteristics (Note 2) I<sub>D</sub> = −1 A, Turn-On Delay Time  $V_{DD} = -5 V$ , 8 16 t<sub>d(on)</sub> ns V<sub>GS</sub> = -4.5 V,  $R_{GEN} = 6 \Omega$ tr Turn–On Rise Time 15 25 ns t<sub>d(off)</sub> Turn–Off Delay Time 45 65 ns tf Turn-Off Fall Time 30 50 ns Q<sub>g</sub> Total Gate Charge  $V_{DS} = -10 V$ ,  $I_{\rm D} = -6 \, {\rm A},$ 13 19 nC  $V_{GS} = -4.5 V$ Qas Gate-Source Charge nC 1.8 Q<sub>gd</sub> Gate-Drain Charge 3 nC **Drain–Source Diode Characteristics and Maximum Ratings** Maximum Continuous Drain-Source Diode Forward Current -2.5 А  $I_S$ Drain-Source Diode Forward  $V_{\text{SD}}$  $V_{GS} = 0 V$ ,  $I_S = -2.5 A$  (Note 2) -0.75 -1.2 V Voltage Notes: 1. R<sub>BLA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta,IC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design. a) 42°C/W when b) 95°/W when mounted c) 110°/W when mounted on a mounted on a 1in<sup>2</sup> on a .0066 in<sup>2</sup> pad of minimum pad. pad of 2 oz copper 2 oz copper

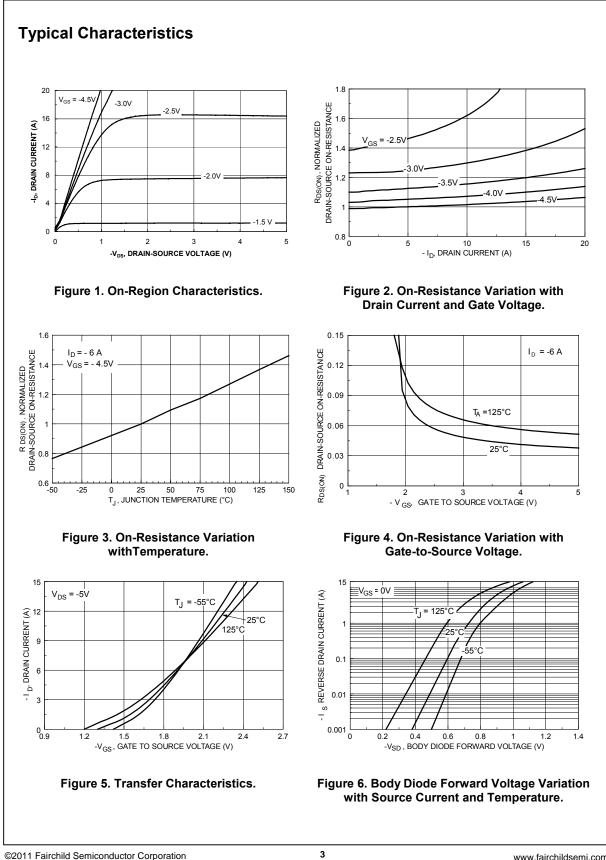
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Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%

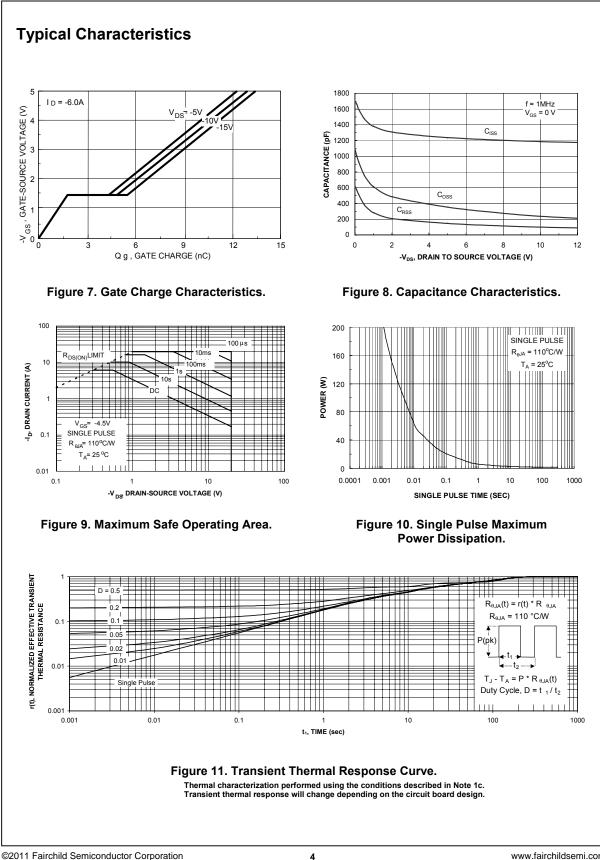
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